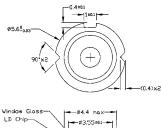
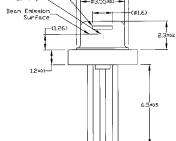
AIGaInP Visible Laser Diode ADL-63103TR/TL

635nm 10mW 40°C Reliable Operation

- •Features
 - 1. High visibility
 - 2. MTTF > 5000hrs
 - 3. Small perpendicular divergence angle
- Applications
 - 1. Industrial laser markers
 - 2. Survey and engineering instruments
 - 3. Class I, eye-safe laser pointer
 - 4. High visibility LD display

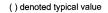


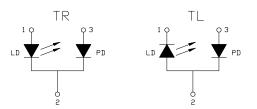




Absolute maximum ratings

Parameter	Symbol Condition		Rating	Unit
Light output power	Po	CW	12	mW
Reverse voltage (LD)	V _{RL}	-	2	V
Reverse voltage (PD)	V _{RD}	-	30	V
Forward current (PD)	I _{FD}	-	10	mA
Case temperature	T _c	-	-10~+40	°C
Storage temperature	Τs	-	-40~+75	°C





•Electrical and optical characteristics (T_c=25 °C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Peak wavelength		630	638.5	642	nm	P _o =10mW
Threshold current	I _{th}	-	30	40	mA	
Operating current	I₀p	-	50	60	mA	P _o =10mW
Operating voltage	V _{op}	-	2.15	2.5	V	P _o =10mW
Differential efficiency		0.30	0.50	0.70	mW/mA	P₀=5-10mW
Monitor current	l _m	0.03	0.1	0.5	mA	P _o =10mW, V _{RD} =5V
Parallel divergence angle	//	6	7.5	11	deg	
Perpendicular divergence angle		25	28.5	35	deg	
Parallel FFP deviation angle	//	_	-	±2.9	deg	P₀=10mW
Perpendicular FFP deviation angle		-	-	±2.9	deg	
Emission point accuracy	хуz	-	-	±80	um	

Precautions

 Do not operate the device above the maximum rating condition, even momentarily. It may cause unexpected permanent damage to the device.
Semiconductor laser device is very sensitive to electrostatic discharge. High voltage spike current may change the characteristics of the device, or malfunction at any time during its service period. Therefore, proper measures for preventing electrostatic discharge are strongly recommended.
Effective heat sink can help the device operates under a more relax condition; as a result, a more stable characteristics and better reliability can be achieved. So it is recommended that always apply proper heat sink before the device is operating.